PACKAGE DIMENSIONS INCH [mm]


TO-8 PACKAGE
ACTIVE AREA $=31.00 \mathrm{~mm}^{2}$

## FEATURES

- High speed
- U.V. enhanced
- Low capacitance
- Quartz window


## DESCRIPTION

The PDU-C108-Q is a silicon, PIN planar diffused, U.V. enhanced photodiode. Ideal for high speed photoconductive applications. Packaged in a TO-8 metal can with a flat quartz window.

## APPLICATIONS

- Spectrometers
- Fluorescent analysers
- U.V. meters
- Colorimeters

SPECTRALRESPONSE
ABSOLUTE MAXIMUM RATING (TA $=25^{\circ} \mathrm{C}$ unless otherwise noted)

| SYMBOL | PARAMETER | MIN | MAX | UNITS |
| :---: | :--- | :---: | :---: | :---: |
| $\mathrm{V}_{\text {BR }}$ | Reverse Voltage |  | 30 | V |
| $\mathrm{~T}_{\text {STG }}$ | Storage Temperature | -55 | +150 | $\circ$ |
| $\mathrm{~T}_{\sigma}$ | Operating Temperature Range | -40 | +125 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{s}}$ | Soldering Temperature* |  | +240 | ${ }^{*} \mathrm{C}$ |
| $\mathrm{I}_{\mathrm{L}}$ | Light Current |  | 500 | mA |

*1/16 inch from case for 3 secs max


WAVELENGTH(nm)

ELECTRO-OPTICAL CHARACTERISTICS (TA $=25^{\circ} \mathrm{C}$ unless otherwise noted)

| SYMBOL | CHARACTERISTIC | TESTCONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Isc | Short Circuit Current | H = $100 \mathrm{fc}, 2850 \mathrm{~K}$ | 400 | 460 |  | $\mu \mathrm{A}$ |
| 1 D | Dark Current | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=5 \mathrm{~V}$ |  | 5 | 15 | pA |
| Rsh | Shunt Resistance | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=10 \mathrm{mV}$ | 32 | 60 |  | M $\Omega$ |
| TC Rsh | Rsp Temp. Coefficient | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=10 \mathrm{mV}$ |  | -8 |  | \% / ${ }^{\circ} \mathrm{C}$ |
| CJ | Junction Capacitance | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=5 \mathrm{~V}^{* *}$ |  | 350 |  | pF |
| $\lambda$ range | Spectral Application Range | Spot Scan | 190 |  | 1100 | nm |
| R | Responsivity | $\mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}, \lambda=254 \mathrm{~nm}$ | . 12 | . 18 |  | A/W |
| Vbr | Breakdown Voltage | $\mathrm{I}=10 \mu \mathrm{~A}$ | 15 | 25 |  | V |
| NEP | Noise Equivalent Power | $\mathrm{V}_{\mathrm{R}}=10 \mathrm{mV}$ @ Peak |  | $4 \times 10^{-14}$ |  | $\mathrm{W} / \sqrt{\mathrm{Hz}}$ |
| tr | Response Time | $\mathrm{RL}=1 \mathrm{~K} \Omega \mathrm{~V}_{\mathrm{R}}=5 \mathrm{~V}$ |  | 110 |  | nS |

Information inthistechnical datasheet is believed to becorrectand reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice. ${ }^{* * f}=1 \mathrm{MHz}$
[FORM NO. 100-PDU-C108-Q REV N/C]

